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August 20, 2003

In Affiliation with
Weiss, Moy & Harris, PC
having offices in Arizona and Nevada,
and in Washington, DC with
Rabin & Berdo. PC

Mail Stop Patent Application

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Attorney Reference: COR 131

Re: New Patent Application of: Mu-Yi Liu, Chih-Chieh Yeh, Tso-Hung Fan

And Tao-Cheng Lu

Title: ONO FLASH MEMORY ARRAY FOR IMPROVING A DISTURBANCE

BETWEEN ADJACENT MEMORY CELLS

Sir:

Please find attached hereto an application for patent which includes:

- [x] Specification, Claims and Abstract (11 Pages)
- [x] 5 Sheets of Formal Drawings (Fig. 1 through Fig. 5)
- [x] Inventor's Declaration and Power of Attorney (4 Pages)
- [x] Assignment document with cover page (4 Pages)
- [x] Fee (see formula below)
- [x] Form PTO-2038

Basic Fee \$750/375 Additional Fees:	\$750.00
Total number of claims:3 in excess of 20: _0_ times \$18/9	\$0.00
Number of independent claims: _2 in excess of 3: _0_ times \$84/42	\$0.00
Multiple Dependent Claims \$280/140	\$0.00
Recording Fee \$40.	\$40.00

TOTAL FEES FOR THE ABOVE APPLICATION

\$ __790.00

In the event there is attached hereto no check or form PTO-2038 (credit card payment form), or a check or form for an insufficient amount, please charge the fee to our Account No. 18-0002 and notify us accordingly.

Respectfully submitted,

Steven M. Rabin (Reg. No. 29,102)

SMR:QZ:tl

